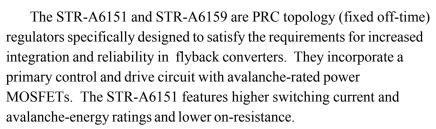
# STR-A6151 AND STR-A6159

Data Sheet **28103.22**\*

# Universal-Input/13 or 16 W Flyback Switching Regulators



Covering the power range from below 13 watts to 16 watts for a 230 VAC input, or 10 to 12 watts for a universal (85 to 264 VAC) input, these devices can be used in a range of applications, from DVD and VCR players to ac adapters for cellular phones and digital cameras. An auto-standby function reduces power consumption at light load, while multiple protections, including the avalanche-energy guaranteed MOSFET, provide high reliability of system design.

Cycle-by-cycle current limiting, undervoltage lockout with hysteresis, overvoltage protection, and thermal shutdown protect the power supply during the normal overload and fault conditions. Overvoltage protection and thermal shutdown are latched after a short delay. The latch may be reset by cycling the input supply. Low start-up current and a low-power standby mode selected from the secondary circuit completes a comprehensive suite of features. Both devices are provided in an 8-pin mini-DIP plastic package.

#### FEATURES AND BENEFITS

- Rugged 650 V Avalanche-Rated MOSFET Simplified Surge Absorption No V<sub>DSS</sub> Derating Required
- Choice of  $\mathbf{r}_{DS(on)}$  (3.95 Ω or 6 Ω maximum)
- Two Operational Modes by Automatic Switching: PRC Mode for Normal Operation Burst Mode for Stand-By Operation or Light Loads
- Built-In Leading Edge Blanking
- Low Start-Up Current
  Start-Up Circuit Disabled in Operation
- Low Operating Current (1.5 mA typ)
- Automatic Burst Stand-By (intermittent operation) Input Power <0.1 W at No Load

-continued

Always order by complete part number, e.g., STR-A6151



## ABSOLUTE MAXIMUM RATINGS at $T_{\Delta} = +25^{\circ}C$

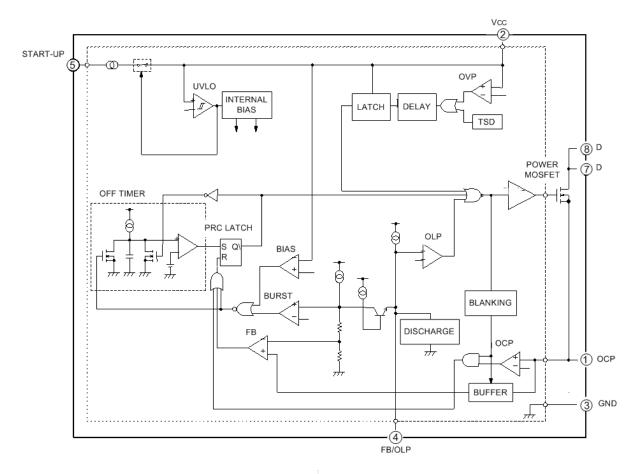
at $I_A = +25^{\circ}C$
Control Supply Voltage, V <sub>CC</sub> <b>35 V</b>
Drain-Source Voltage, V <sub>DSS</sub> <b>650 V</b>
Drain Switching Current, I <sub>D</sub>
STR-A6151 2.5 A*
STR-A6159 1.8 A*
Peak Drain Switching Current, IDM
STR-A6151 2.5 A
STR-A6159 1.8 A
Single-Pulse Avalanche Energy, E <sub>AS</sub>
STR-A6151
STR-A6159 24 mJ
Start-Up-Pin Voltage Range,
V <sub>startup</sub> 0.3 V to +600 V
OCP Voltage Range,
V <sub>OCP</sub> <b>–0.5 V to +6 V</b>
FB/OLP Voltage Range,
V <sub>FB/OLP</sub> <b>–0.5</b> V to <b>+10</b> V
Package Power Dissipation, P <sub>D</sub>
control $(V_{CC} \times I_{CC(ON)})$ 0.15 W
MOSFET (V <sub>DSS</sub> × I <sub>D</sub> ) <b>1.35 W</b>
total 1.5 W
MOSFET Channel Temp., T <sub>J</sub> . +150°C
Internal Frame Temp., T <sub>F</sub> +125°C
Operating Temperature Range,
T <sub>A</sub> 20°C to +125°C†
Storage Temperature Range,
T <sub>S</sub> 40°C to +125°C

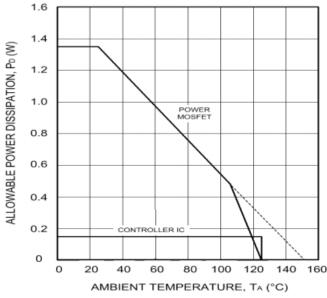
perature (page 2) and safe operating area (page 4).

†For the availability of parts meeting -40°C requirements, contact Sanken's Sales Representative.



#### **FUNCTIONAL BLOCK DIAGRAM**





#### FEATURES AND BENEFITS (cont'd)

- Auto-Bias Function
  Stable Burst Operation Without Generating Interference
- Internal Off-Timer Circuit
- Built-In Constant-Voltage Drive
- Multiple Protections:
  Pulse-by-Pulse Overcurrent Protection
  Overload Protection with Auto Recovery
  Latching Overvoltage Protection
  Undervoltage Lockout with Hysteresis
  Latching Thermal Shutdown
- Molded Small-Size 8-Pin Package
  For Low-Height SMPS
  Polarized to Prevent Backwards Assembly



## STR-A6151 and STR-A6159 Universal-Input/13 or 16 W Flyback Switching Regulators

#### **ELECTRICAL CHARACTERISTICS** at $T_A = 25$ °C, $V_{CC} = 20$ V (unless otherwise specified).

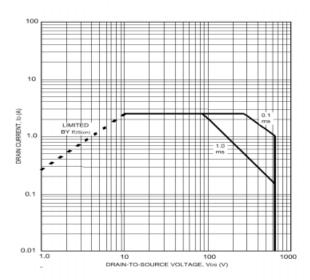
	Pin			Ratings			
Characteristic	No.	Symbol	Test Conditions	Min	Тур	Max	Units
Drain-to-Source Breakdown Volt.	8 - 1	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 300 μA,	650	-	-	V
		,	$V_1 - V_3 = 0 V $ (short)				
Drain Leakage Current	8 - 1	I <sub>DSS</sub>	V <sub>DS</sub> = 650 V,	-	-	300	μA
			$V_1 - V_3 = 0 V (short)$				
On-State Resistance	8 - 1	r <sub>DS(on)</sub>	STR-A6151, I <sub>D</sub> = 0.4 A	-	-	3.95	Ω
		, ,	STR-A6159, I <sub>D</sub> = 0.4 A	-	-	6.00	Ω
MOSFET Switching Time	8 - 3	t <sub>f</sub>	-	-	-	250	ns
Operation Start Voltage	2 - 3	V <sub>CC(ON)</sub>	V <sub>CC</sub> = 0 → 19.2 V	16	17.5	19.2	V
Operation Stop Voltage	2 - 3	$V_{CC(OFF)}$	V <sub>CC</sub> = 19.2 → 9 V	9.0	10	11	V
Circuit Current in Operation	2 - 3	I <sub>CC(ON)</sub>	-	-	-	4.0	mA
Circuit Current in Non-Operation	2 - 3	I <sub>CC(OFF)</sub>	V <sub>CC</sub> = 14 V	-	-	50	μΑ
Auto-Bias Threshold Voltage	2 - 3	$V_{CC(bias)}$	V <sub>CC</sub> = 20 → 9.6 V	9.6	10.6	11.6	V
V <sub>CC(bias)</sub> - V <sub>CC(OFF)</sub>	1	-	-	0.2	0.6	-	V
Maximum OFF Time	8 - 3	$t_{OFF}$	-	7.3	8.0	8.7	μs
OCP Threshold Voltage	1 - 3	$V_{OCP}$	-	0.69	0.77	0.86	V
Leading Edge Blanking Time	8 - 3	$t_b$	-	200	320	480	ns
Burst Threshold Voltage	4 - 3	$V_{\text{burst}}$		0.70	0.79	0.88	V
OLP Threshold Voltage	4 - 3	$V_{OLP}$	-	6.5	7.2	7.9	V
Current at OLP Operation	4 - 3	$I_{OLP}$	-	-18	-26	-35	μΑ
Maximum FB Current	4 - 3	I <sub>FB(MAX)</sub>	-	227	300	388	μΑ
Start-Up Current	5 - 3	I <sub>startup</sub>	V <sub>CC</sub> = 15 V	340	790	1230	μΑ
Start-Up Circuit Leakage Current	5 - 3	I <sub>start(leak)</sub>	-	-	-	30	μΑ
OVP Operation Voltage	2 - 3	V <sub>CC(OVP)</sub>	V <sub>CC</sub> = 0 → 34.1 V	28.7	31.2	34.1	V
OVP/TSD Latch Sustaining Current	2 - 3	I <sub>CC(H)</sub>	V <sub>CC</sub> =34.1 → 8.5 V	-	-	200	μA
OVP/TSD Latch Release Voltage	2 - 3	V <sub>cc</sub>	V <sub>CC</sub> =34.1 → 6.6 V	6.6	7.3	8.0	V
Thermal Shutdown	-	$T_J$	-	135	-	-	°C
Thermal Resistance	-	$R_{ hetaJF}$	-	-	-	52	°C/W

**WARNING** — These devices are designed to be operated at lethal voltages and energy levels. Circuit designs that embody these components must conform with applicable safety requirements. Precautions must be taken to prevent accidental contact with power-line potentials. Do not connect grounded test equipment.

The use of an isolation transformer is recommended during circuit development and breadboarding.

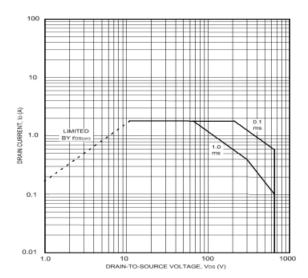
#### **MOSFET TYPICAL CHARACTERISTICS**

#### STR-A6151

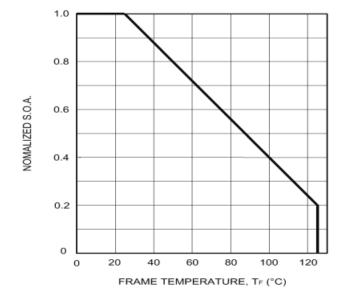


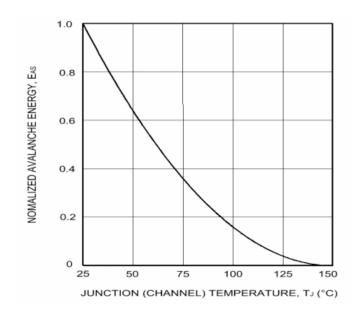
Avalanche energy is measured at  $V_{DD}$  = 99 V, L = 20 mH, I<sub>L</sub> = 2.5 A.

#### STR-A6159



Avalanche energy is measured at  $V_{DD}$  = 99 V, L = 20 mH, I<sub>L</sub> = 1.8 A.

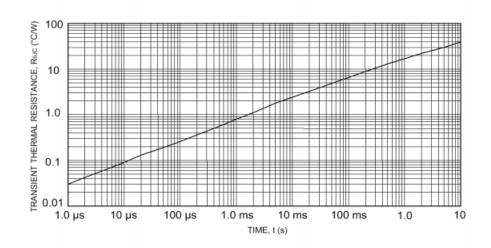




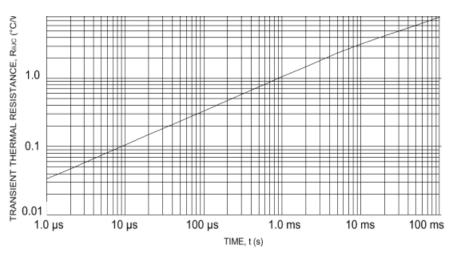


## MOSFET TYPICAL CHARACTERISTICS (cont'd)

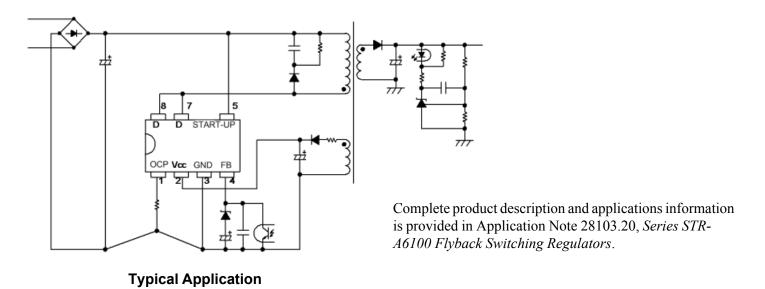
#### STR-A6151



#### STR-A6159



#### **APPLICATIONS INFORMATION**



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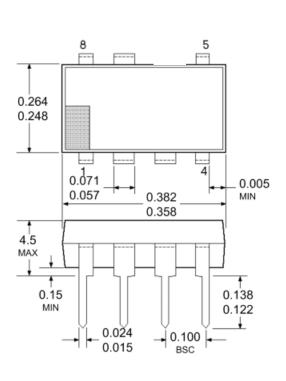
• In the case that you use Sanken products or design your products by using Sanken products, the reliability largely depends on the degree of derating to be made to the rated values. Derating may be interpreted as a case that an operation range is set by derating the load from each rated value or surge voltage or noise is considered for derating in order to assure or improve the reliability. In general, derating factors include electric stresses such as electric voltage, electric current, electric power etc., environmental stresses such as ambient temperature, humidity etc. and thermal stress caused due to self-heating of semiconductor products. For these stresses, instantaneous values, maximum values and minimum values must be taken into consideration.

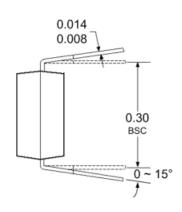
In addition, it should be noted that since power devices or IC's including power devices have large self-heating value, the degree of derating of junction temperature affects the reliability significantly.

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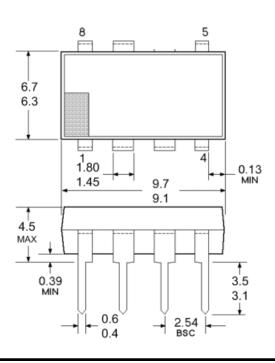
### STR-A6151 and STR-A6159 Universal-Input/13 or 16 W Flyback Switching Regulators

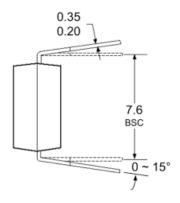
#### **PACKAGE DIMENSIONS**





Dimensions in Inches (for reference only)





**Dimensions in Millimeters** (controlling dimensions)

Product Weight: Approx. 0.51 g. Frame temperature,  $T_{\text{F}}$ , is measured at the root of pin 3.